

L Number	Hits	Search Text	DB	Time stamp
1	144	isolation with silicon adj carbide	USPAT; EPO; JPO; DERWENT	2004/08/19 11:29
2	0	isolation with (silicon adj carbide) and insulat\$3 near2 conductivity	USPAT; EPO; JPO; DERWENT	2004/08/19 11:29
3	144	isolation with (silicon adj carbide)	USPAT; EPO; JPO; DERWENT	2004/08/19 11:30
4	29	(isolation with (silicon adj carbide)) and MOSFET	USPAT; EPO; JPO; DERWENT	2004/08/19 11:30